

DARLINGTON POWER TRANSISTOR 2SC4351

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING

The 2SC4351 is a high-speed Darlington power transistor. This transistor is ideal for high-precision control such as PWM control for pulse motors or blushless motor of OA and FA equipment.

FEATURES

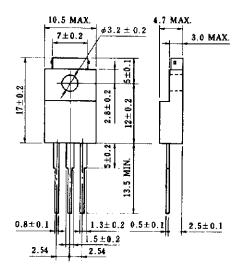
- Mold package that does not require an insulating board or insulation bushing
- On-chip C to B constant voltage diode for surge voltage absorption
- On-chip C to E reverse diode
- · Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V _{СВО}	60 ± 10	V	
Collector to emitter voltage	VCEO	60 ± 10	V	
Emitter to base voltage	V _{EBO}	8.0	V	
Collector current (DC)	Ic(DC)	±5.0	Α	
Collector current (pulse)	Ic(pulse)*	±10	Α	
Base current (DC)	I _{B(DC)}	0.5	Α	
Total power dissipation	P⊤ (Tc = 25°C)	20	W	
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

^{*} PW \leq 10 ms, duty cycle \leq 50%

PACKAGE DRAWING (UNIT: mm)

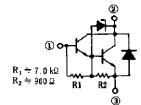




Electrode Connection

1. Base

Collector
 Emitter



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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = 40 V, IE = 0			0.5	μΑ
DC current gain	h _{FE1} *	Vce = 2.0 V, Ic = 2.0 A	2,000		20,000	
DC current gain	h _{FE2} *	Vce = 2.0 V, Ic = 4.0 A	500			
Collector saturation voltage	V _{CE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA			1.5	V
Base saturation voltage	V _{BE(sat)} *	Ic = 2.0 A, I _B = 2.0 mA			2.0	V
Turn-on time	ton	$\begin{aligned} &\text{Ic} = 2.0 \text{ A, I}_{\text{B1}} = -\text{I}_{\text{B2}} = 2.0 \text{ mA,} \\ &\text{RL} = 25 \Omega, \text{ Vcc} \cong 50 \text{ V} \\ &\text{Refer to the test circuit.} \end{aligned}$		0.7		μs
Storage time	tstg			2.5		μs
Fall time	t _f			0.6		μs

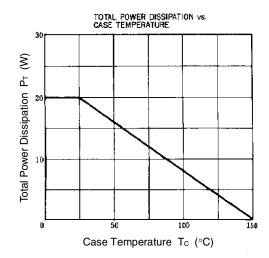
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

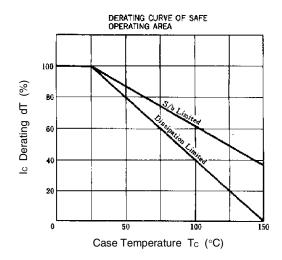
hfe CLASSIFICATION

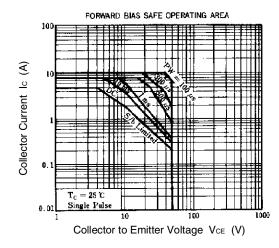
Marking	М	L	К
h _{FE1}	2,000 to 5,000	4,000 to 10,000	8,000 to 20,000

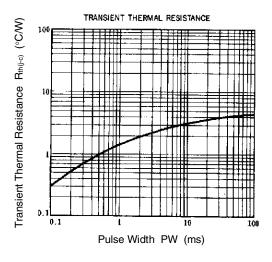


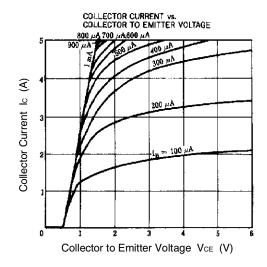
TYPICAL CHARACTERISTICS (Ta = 25°C)

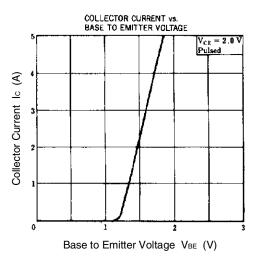




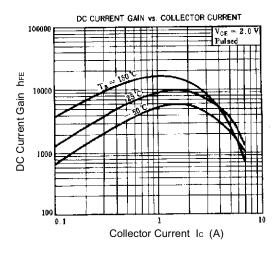


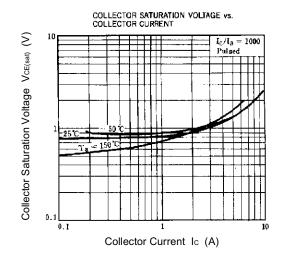


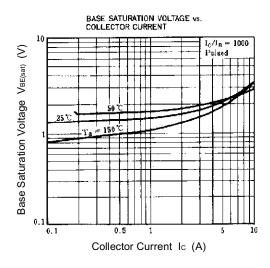


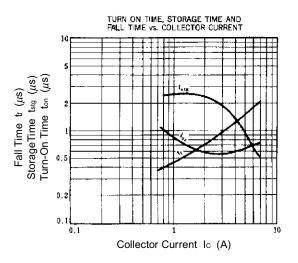


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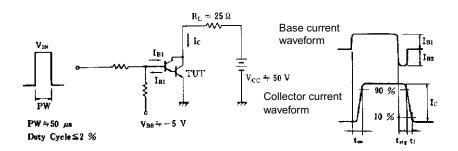








SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT





[MEMO]

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